



# N-Channel Enhancement-Mode Vertical DMOS FET

## Features

- ▶ Free from secondary breakdown
- ▶ Low power drive requirement
- ▶ Ease of paralleling
- ▶ Low  $C_{ISS}$  and fast switching speeds
- ▶ High input impedance and high gain

## Applications

- ▶ Motor controls
- ▶ Converters
- ▶ Amplifiers
- ▶ Switches
- ▶ Power supply circuits
- ▶ Drivers (relays, hammers, solenoids, lamps, memories, displays, bipolar transistors, etc.)

## General Description

This low threshold, enhancement-mode (normally-off) transistor utilizes a vertical DMOS structure and Supertex's well-proven, silicon-gate manufacturing process. This combination produces a device with the power handling capabilities of bipolar transistors and the high input impedance and positive temperature coefficient inherent in MOS devices. Characteristic of all MOS structures, this device is free from thermal runaway and thermally-induced secondary breakdown.

Supertex's vertical DMOS FETs are ideally suited to a wide range of switching and amplifying applications where very low threshold voltage, high breakdown voltage, high input impedance, low input capacitance, and fast switching speeds are desired.

## Ordering Information

Part Number	Package Option	Packing
VN2110K1-G	TO-236AB (SOT-23)	3000/Reel

-G denotes a lead (Pb)-free / RoHS compliant package.  
 Contact factory for Wafer / Die availability.  
 Devices in Wafer / Die form are lead (Pb)-free / RoHS compliant.

## Product Summary

$BV_{DSS} / BV_{DGS}$	$R_{DS(ON)}$ (max)
100V	4.0Ω

## Absolute Maximum Ratings

Parameter	Value
Drain-to-source voltage	$BV_{DSS}$
Drain-to-gate voltage	$BV_{DGS}$
Gate-to-source voltage	±20V
Operating and storage temperature	-55°C to +150°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied. Continuous operation of the device at the absolute rating level may affect device reliability. All voltages are referenced to device ground.

## Pin Configuration



## Typical Thermal Resistance

Package	$\theta_{ja}$
TO-236AB (SOT-23)	203°C/W

## Product Marking



W = Code for Week Sealed  
 — = "Green" Packaging

Package may or may not include the following marks: Si or **TO-236AB (SOT-23)**

## Thermal Characteristics

Package	$I_D$ (continuous) <sup>†</sup>	$I_D$ (pulsed)	Power Dissipation @ $T_c = 25^\circ\text{C}$	$I_{DR}$ <sup>†</sup>	$I_{DRM}$
TO-236AB (SOT-23)	200mA	800mA	0.36W	200mA	800mA

### Notes:

<sup>†</sup>  $I_D$  (continuous) is limited by max rated  $T_j$ .

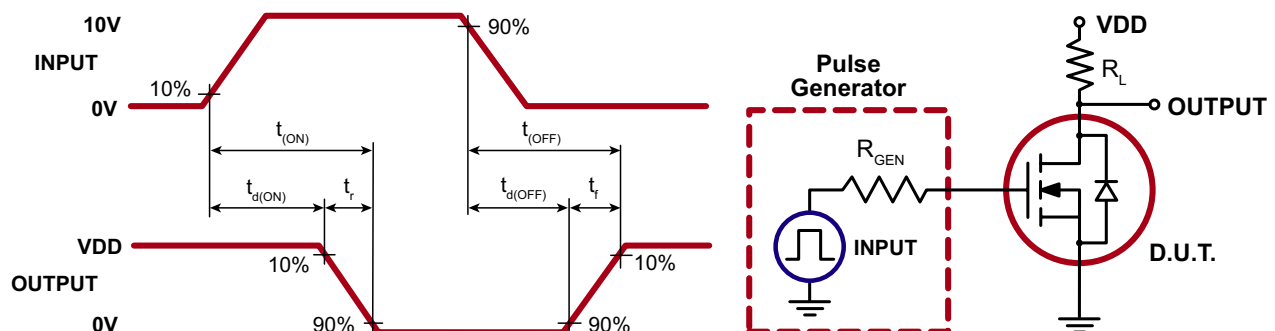
## Electrical Characteristics ( $T_A = 25^\circ\text{C}$ unless otherwise specified)

Sym	Parameter	Min	Typ	Max	Units	Conditions
$BV_{DSS}$	Drain-to-source breakdown voltage	100	-	-	V	$V_{GS} = 0V, I_D = 1.0mA$
$V_{GS(th)}$	Gate threshold voltage	0.8	-	2.4	V	$V_{GS} = V_{DS}, I_D = 1.0mA$
$\Delta V_{GS(th)}$	Change in $V_{GS(th)}$ with temperature	-	-3.8	-5.5	mV/ $^\circ\text{C}$	$V_{GS} = V_{DS}, I_D = 1.0mA$
$I_{GSS}$	Gate body leakage current	-	0.1	100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
$I_{DSS}$	Zero gate voltage drain current	-	-	1.0	$\mu\text{A}$	$V_{GS} = 0V, V_{DS} = \text{Max Rating}$
		-	-	100		$V_{DS} = 0.8 \text{ Max Rating}, V_{GS} = 0V, T_A = 125^\circ\text{C}$
$I_{D(ON)}$	On-state drain current	0.6	-	-	A	$V_{GS} = 10V, V_{DS} = 25V$
$R_{DS(ON)}$	Static drain-to-source on-state resistance	-	4.5	6.0	$\Omega$	$V_{GS} = 5.0V, I_D = 75mA$
		-	3.0	4.0		$V_{GS} = 10V, I_D = 500mA$
$\Delta R_{DS(ON)}$	Change in $R_{DS(ON)}$ with temperature	-	0.7	1.0	%/ $^\circ\text{C}$	$V_{GS} = 10V, I_D = 500mA$
$G_{FS}$	Forward transconductance	150	400	-	mmho	$V_{DS} = 25V, I_D = 500mA$
$C_{ISS}$	Input capacitance	-	35	50	pF	$V_{GS} = 0V,$ $V_{DS} = 25V,$ $f = 1.0MHz$
$C_{OSS}$	Common source output capacitance	-	13	25		
$C_{RSS}$	Reverse transfer capacitance	-	4.0	5.0		
$t_{d(ON)}$	Turn-on delay time	-	3.0	5.0	ns	$V_{DD} = 25V,$ $I_D = 600mA,$ $R_{GEN} = 25\Omega$
$t_r$	Rise time	-	5.0	8.0		
$t_{d(OFF)}$	Turn-off delay time	-	6.0	9.0		
$t_f$	Fall time	-	5.0	8.0		
$V_{SD}$	Diode forward voltage drop	-	1.2	1.8	V	$V_{GS} = 0V, I_{SD} = 600mA$
$t_{rr}$	Reverse recovery time	-	400	-	ns	$V_{GS} = 0V, I_{SD} = 600mA$

### Notes:

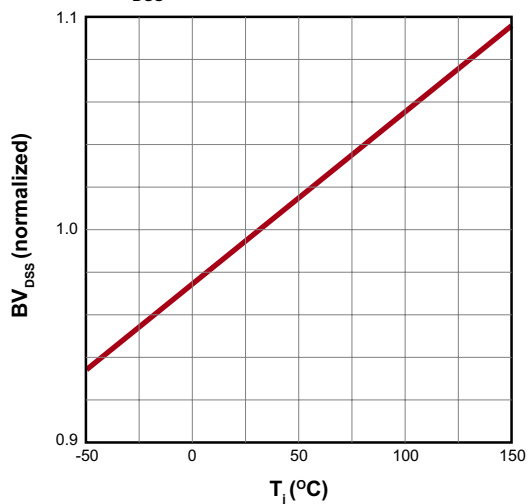
- All D.C. parameters 100% tested at  $25^\circ\text{C}$  unless otherwise stated. (Pulse test: 300 $\mu\text{s}$  pulse, 2% duty cycle.)
- All A.C. parameters sample tested.

## Switching Waveforms and Test Circuit

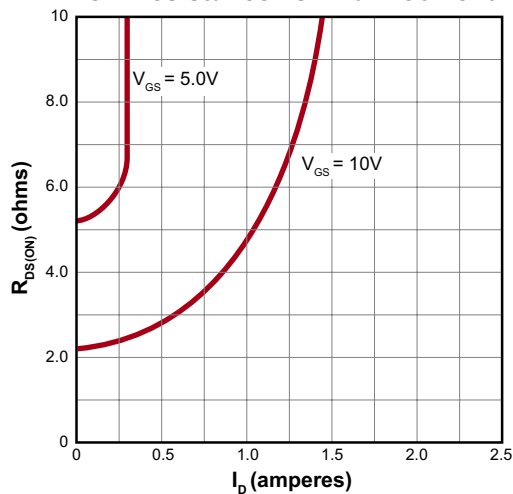


# Typical Performance Curves

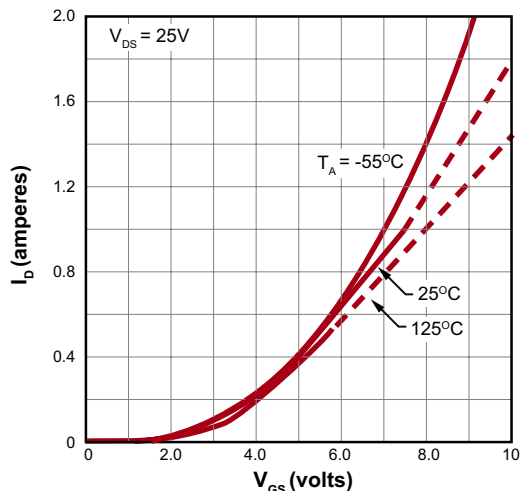
**BV<sub>DSS</sub> Variation with Temperature**



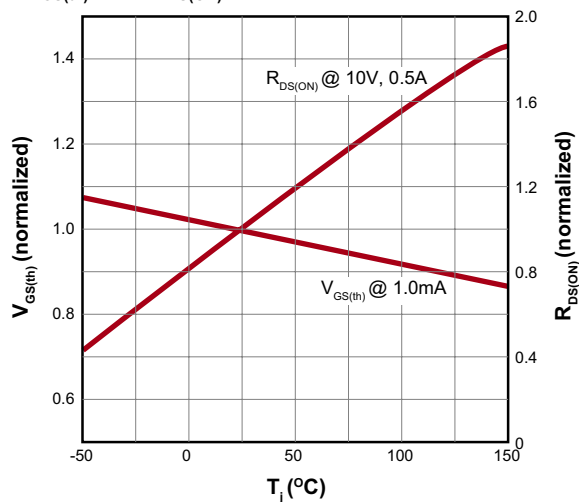
**On-Resistance vs. Drain Current**



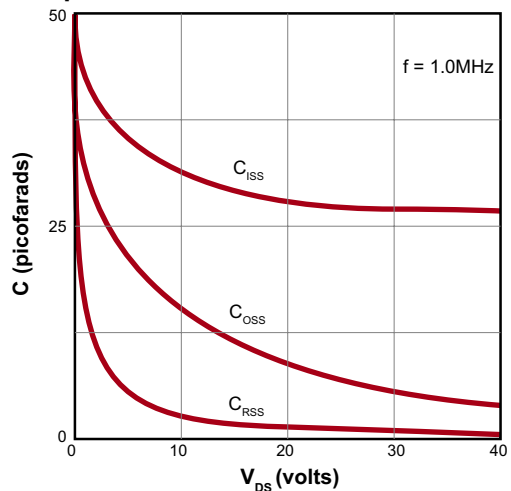
**Transfer Characteristics**



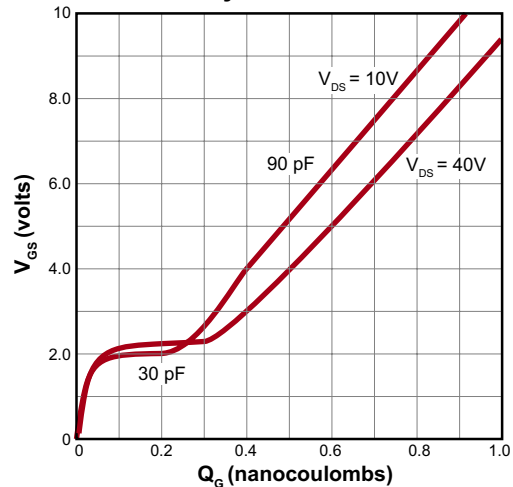
**V<sub>GS(th)</sub> and R<sub>DS(ON)</sub> Variation with Temperature**



**Capacitance vs. Drain-to-Source Voltage**

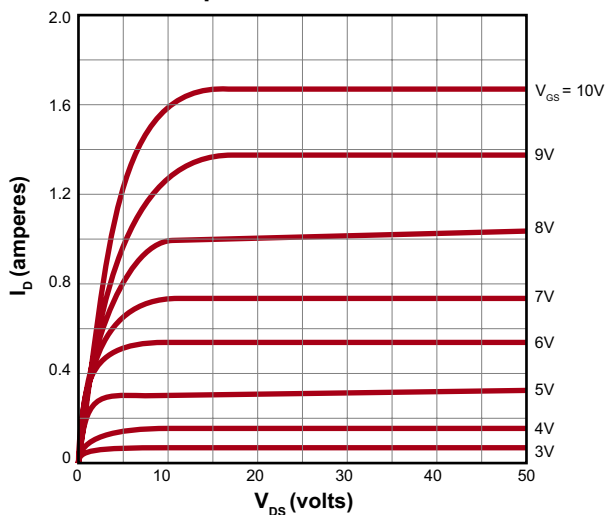


**Gate Drive Dynamic Characteristics**

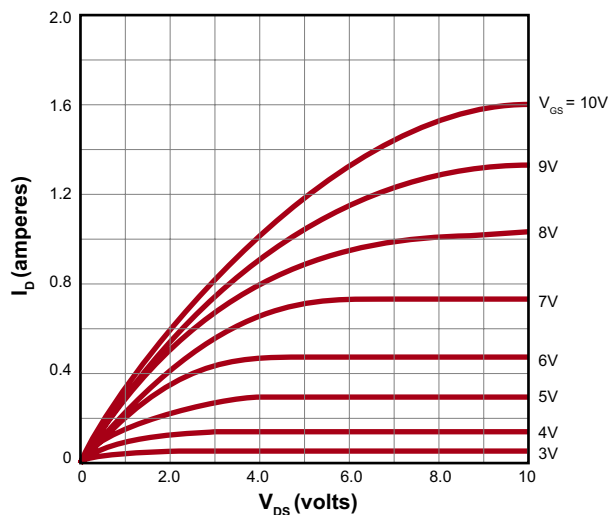


Typical Performance Curves (cont.)

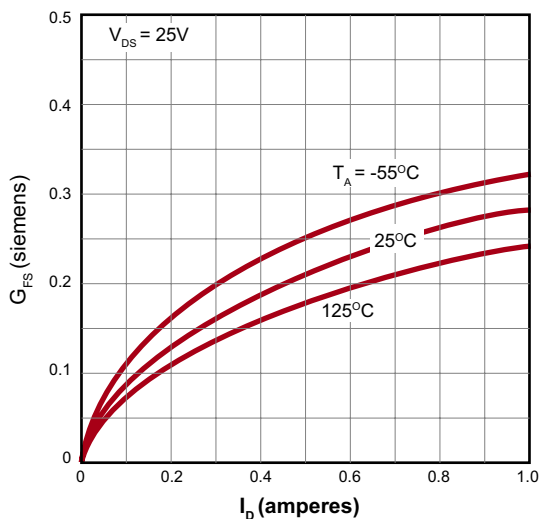
Output Characteristics



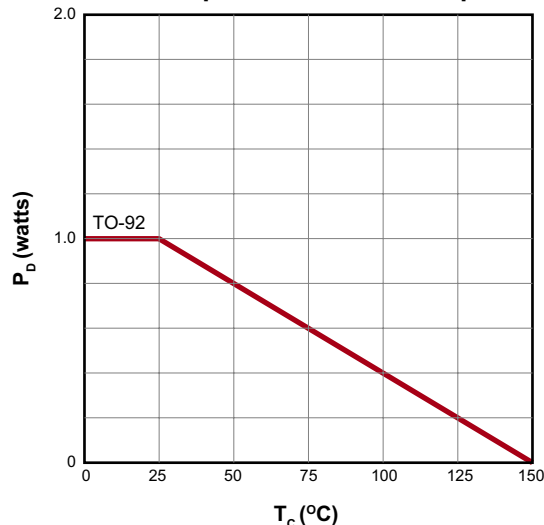
Saturation Characteristics



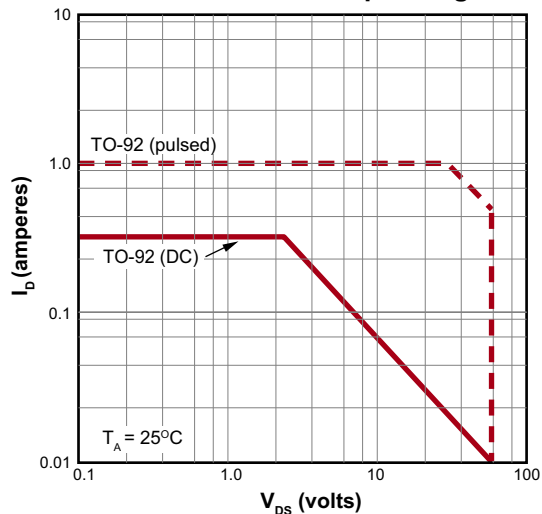
Transconductance vs. Drain Current



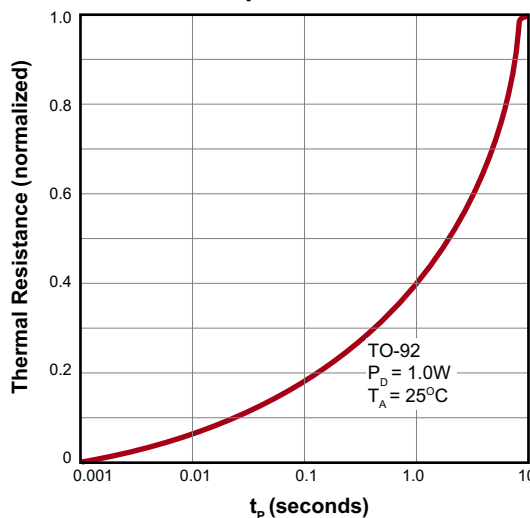
Power Dissipation vs. Case Temperature



Maximum Rated Safe Operating Area

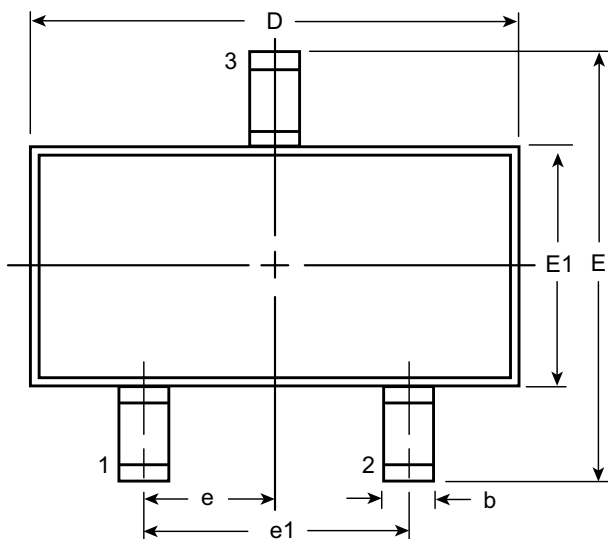


Thermal Response Characteristics

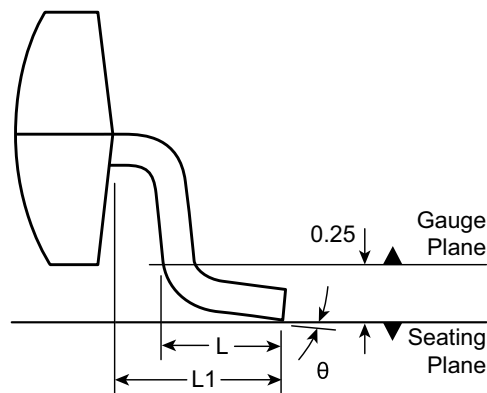


### 3-Lead TO-236AB (SOT-23) Package Outline (K1)

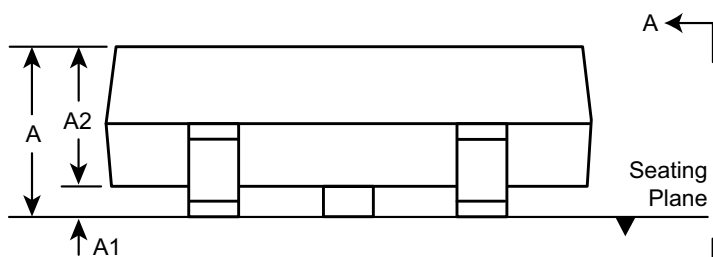
2.90x1.30mm body, 1.12mm height (max), 1.90mm pitch



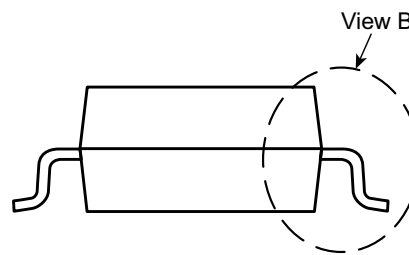
**Top View**



**View B**



**Side View**



**View A - A**

Symbol	A	A1	A2	b	D	E	E1	e	e1	L	L1	$\theta$	
Dimension (mm)	MIN	0.89	0.01	0.88	0.30	2.80	2.10	1.20	0.95 BSC	1.90 BSC	0.20 <sup>†</sup> 0.50 0.60	0.54 REF	0°
	NOM	-	-	0.95	-	2.90	-	1.30					-
	MAX	1.12	0.10	1.02	0.50	3.04	2.64	1.40					8°

JEDEC Registration TO-236, Variation AB, Issue H, Jan. 1999.

<sup>†</sup> This dimension differs from the JEDEC drawing.

Drawings not to scale.

Supertex Doc.#: DSPD-3TO236ABK1, Version C041309.

(The package drawing (s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to <http://www.supertex.com/packaging.html>.)

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